

Is Now Part of



# **ON Semiconductor**®

# To learn more about ON Semiconductor, please visit our website at <u>www.onsemi.com</u>

Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (\_), the underscore (\_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (\_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at <a href="https://www.onsemi.com">www.onsemi.com</a>. Please email any questions regarding the system integration to <a href="https://www.onsemi.com">Fairchild\_questions@onsemi.com</a>.

ON Semiconductor and the ON Semiconductor logo are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized applications, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the design or manufacture of the part. ON Semiconductor is an equif prese



# FGH50T65SQD 650 V, 50 A Field Stop Trench IGBT

## **Features**

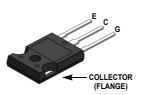
- Maximum Junction Temperature : T<sub>J</sub> =175°C
- · Positive Temperaure Co-efficient for Easy Parallel Operating
- · High Current Capability
- Low Saturation Voltage: V<sub>CE(sat)</sub> =1.6 V(Typ.) @ I<sub>C</sub> = 50 A
- 100% of the Parts Tested for I<sub>LM</sub>(1)
- · High Input Impedance
- Fast Switching
- Tighten Parameter Distribution
- · RoHS Compliant

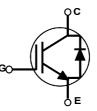
## **General Description**

Using novel field stop IGBT technology, Fairchild's new series of field stop 4<sup>th</sup> generation IGBTs offer the optimum performance for solar inverter, UPS, welder, telecom, ESS and PFC applications where low conduction and switching losses are essential.

## Applications

· Solar Inverter, UPS, Welder, Telecom, ESS, PFC





## **Absolute Maximum Ratings**

Symbol	Description		FGH50T65SQD_F155	Unit
V <sub>CES</sub>	Collector to Emitter Voltage		650	V
V <sub>GES</sub>	Gate to Emitter Voltage		± 20	V
	Transient Gate to Emitter Voltage		± 30	V
I <sub>C</sub>	Collector Current	@ T <sub>C</sub> = 25°C	100	А
ιC.	Collector Current	@ T <sub>C</sub> = 100 <sup>o</sup> C	50	А
I <sub>LM (1)</sub>	Pulsed Collector Current	@ T <sub>C</sub> = 25°C	200	А
I <sub>CM (2)</sub>	Pulsed Collector Current		200	А
I <sub>F</sub>	Diode Forward Current	@ T <sub>C</sub> = 25°C	50	А
	Diode Forward Current	@ T <sub>C</sub> = 100 <sup>o</sup> C	30	А
I <sub>FM</sub>	Pulsed Diode Maximum Forward Curr	200	А	
P <sub>D</sub>	Maximum Power Dissipation	@ T <sub>C</sub> = 25°C	268	W
. D	Maximum Power Dissipation	@ T <sub>C</sub> = 100 <sup>o</sup> C	134	W
TJ	Operating Junction Temperature		-55 to +175	°C
T <sub>stg</sub>	Storage Temperature Range		-55 to +175	°C
TL	Maximum Lead Temp. for soldering Purposes, 1/8" from case for 5 seconds		300	°C

Notes: 1.  $V_{CC}$  = 400 V,  $V_{GE}$  = 15 V,  $I_{C}$  = 200 A,  $R_{G}$  = 3  $\Omega,$  Inductive Load

2. Repetitive rating: Pulse width limited by max. junction temperature

April 2016

Symbo	ol 🛛	P	arameter	r FGH		50T6	5SQD_F155		Unit	
R <sub>0JC</sub> (IGBT)	Therm	al Resistance, Jur	nction to Case	se, Max.		0.56			°C/W	
R <sub>0JC</sub> (Diode	) Therm	Thermal Resistance, Junction to Ca		e, Max.		1.25			°C/W	
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction to An			ient, Max.			40		°C/W	
Package	e Markir	ng and Orde	ering Inf	ormation						
Part N		Top Mark	Package		dReel	Size	Tape Widtl	n Qty p	er Tube	
FGH50T65	SQD_F155	FGH50T65SQD	TO-247 G0	3 Tube	-		-		30	
Electric	al Chara	acteristics o	of the IG	<b>BT</b> $T_{C} = 25^{\circ}C$ unless other	wise noted					
Symbol		Parameter		Test Conditio	ns	Mi	n. Typ.	Max.	Unit	
Off Charac	teristics									
BV <sub>CES</sub>	Collector to	Emitter Breakdow	vn Voltage	/ <sub>GE</sub> = 0V, I <sub>C</sub> = 1 mA		65	0 -	-	V	
ABV Tomporature Coefficient of Breakdown		reakdown	$I_{\rm C}$ = 1 mA, Reference to 25°C		-	0.6	-	V/ºC		
I <sub>CES</sub>	Collector Cut-Off Current		Ň	V <sub>CE</sub> = V <sub>CES</sub> , V <sub>GE</sub> = 0 V		-	-	250	μA	
I <sub>GES</sub>	G-E Leakage Current		١	$V_{GE}$ = $V_{GES}$ , $V_{CE}$ = 0 V		-	-	±400	nA	
On Charac	teristics									
V <sub>GE(th)</sub>		G-E Threshold Voltage		I <sub>C</sub> = 50 mA, V <sub>CE</sub> = V <sub>GE</sub>		2.0	6 4.5	6.4	V	
			I <sub>C</sub> = 50 A, V <sub>GE</sub> = 15 V, T		<sub>C</sub> = 25°C	-	1.6	2.1	V	
V <sub>CE(sat)</sub>	Collector to	Emitter Saturatio	n Voltage	<sub>C</sub> = 50 A, V <sub>GE</sub> = 15 V, T <sub>C</sub>	<sub>c</sub> = 175°C	-	1.92	-	V	
Dynamic C	haracteristi	cs								
C <sub>ies</sub>	Input Capa	citance				-	3275	-	pF	
C <sub>oes</sub>	Output Cap	Output Capacitance Reverse Transfer Capacitance		V <sub>CE</sub> = 30 V <sub>,</sub> V <sub>GE</sub> = 0 V, f = 1MHz		-	84	-	pF	
C <sub>res</sub>	Reverse Tr					-	12	-	pF	
Switching	Characteris	tics								
t <sub>d(on)</sub>	Turn-On De	elay Time				-	22	-	ns	
t <sub>r</sub>	Rise Time	ïme				-	8.7	-	ns	
t <sub>d(off)</sub>	Turn-Off De	elay Time	١	/ <sub>CC</sub> = 400 V, I <sub>C</sub> = 12.5 A	λ,	-	105	-	ns	
t <sub>f</sub>	Fall Time			$R_G$ = 4.7 Ω, V <sub>GE</sub> = 15 V, Inductive Load, T <sub>C</sub> = 25 <sup>o</sup> C		-	2.5	-	ns	
E <sub>on</sub>	Turn-On Sv	witching Loss	1			-	180	-	uJ	
E <sub>off</sub>	Turn-Off Sv	witching Loss				-	45	-	uJ	
E <sub>ts</sub>	Total Switc	hing Loss				-	225	-	uJ	
t <sub>d(on)</sub>	Turn-On De	elay Time				-	19	-	ns	
t <sub>r</sub>	Rise Time					-	13	-	ns	
t <sub>d(off)</sub>	Turn-Off De	Turn-Off Delay Time Fall Time		/ <sub>CC</sub> = 400 V, I <sub>C</sub> = 25 A,		-	93	-	ns	
t <sub>f</sub>	Fall Time			R <sub>G</sub> = 4.7 Ω, V <sub>GE</sub> = 15 V,		-	6.4	-	ns	
E <sub>on</sub>	Turn-On Sv	witching Loss		Inductive Load, T <sub>C</sub> = 25 <sup>o</sup>	Ċ	-	410	-	uJ	
E <sub>off</sub>	Turn-Off Sv	witching Loss				-	88	-	uJ	
E <sub>ts</sub>	Total Switc	hing Loss				-	498	-	uJ	

Symbol	Parameter	Test Conditions	Min.	Тур.	Max	Unit
t <sub>d(on)</sub>	Turn-On Delay Time		-	20	-	ns
t <sub>r</sub>	Rise Time		-	9.8	-	ns
t <sub>d(off)</sub>	Turn-Off Delay Time	V <sub>CC</sub> = 400 V, I <sub>C</sub> = 12.5 A,	-	116	-	ns
t <sub>f</sub>	Fall Time	$R_{G} = 4.7 \Omega$ , $V_{GE} = 15 V$ ,	-	3.5	-	ns
Eon	Turn-On Switching Loss	Inductive Load, T <sub>C</sub> = 175 <sup>o</sup> C	-	402	-	uJ
E <sub>off</sub>	Turn-Off Switching Loss		-	110	-	uJ
E <sub>ts</sub>	Total Switching Loss		-	512	-	uJ
t <sub>d(on)</sub>	Turn-On Delay Time		-	18	-	ns
t <sub>r</sub>	Rise Time	V <sub>CC</sub> = 400 V, I <sub>C</sub> = 25 A, R <sub>G</sub> = 4.7 Ω, V <sub>GE</sub> = 15 V,	-	15	-	ns
t <sub>d(off)</sub>	Turn-Off Delay Time		-	102	-	ns
t <sub>f</sub>	Fall Time		-	8	-	ns
Eon	Turn-On Switching Loss	Inductive Load, T <sub>C</sub> = 175 <sup>o</sup> C	-	641	-	uJ
E <sub>off</sub>	Turn-Off Switching Loss		-	203	-	uJ
E <sub>ts</sub>	Total Switching Loss		-	844	-	uJ
Qg	Total Gate Charge		-	99	-	nC
Q <sub>ge</sub>	Gate to Emitter Charge	V <sub>CE</sub> = 400 V, I <sub>C</sub> = 50 A, V <sub>GE</sub> = 15 V	-	17	-	nC
Q <sub>gc</sub>	Gate to Collector Charge		-	23	-	nC

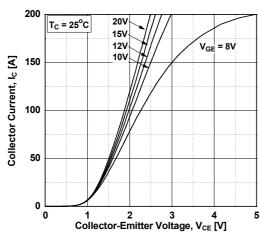
#### ~ ~ . .

## Electrical Characteristics of the Diode T<sub>C</sub> = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions		Min.	Тур.	Max	Unit
V <sub>FM</sub>	Diode Forward Voltage	I <sub>F</sub> = 30 A	T <sub>C</sub> = 25 <sup>o</sup> C	-	2.2	2.6	V
		1 <sub>F</sub> 0077	T <sub>C</sub> = 175 <sup>o</sup> C	-	1.9	-	•
E <sub>rec</sub>	Reverse Recovery Energy		T <sub>C</sub> = 175 <sup>o</sup> C	-	40	-	uJ
t <sub>rr</sub>	Diode Reverse Recovery Time	I <sub>F</sub> =30 A, dI <sub>F</sub> /dt = 200 A/μs	T <sub>C</sub> = 25°C	-	31	-	ns
11			T <sub>C</sub> = 175°C	-	207	-	
Q <sub>rr</sub>	Diode Reverse Recovery Charge		T <sub>C</sub> = 25°C	-	48	-	nC
~11			T <sub>C</sub> = 175 <sup>o</sup> C	-	820	-	

## **Typical Performance Characteristics**







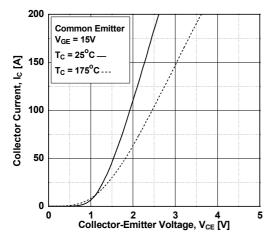


Figure 5. Saturation Voltage vs.  $V_{GE}$ 

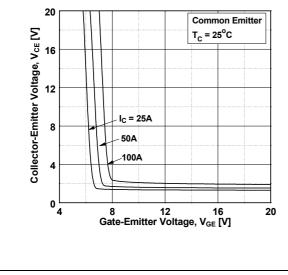
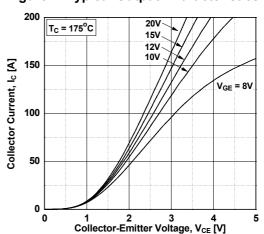


Figure 2. Typical Output Characteristics





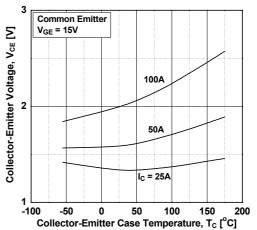
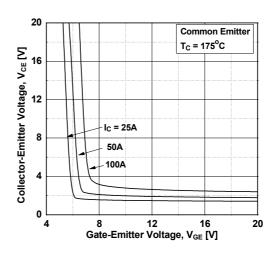
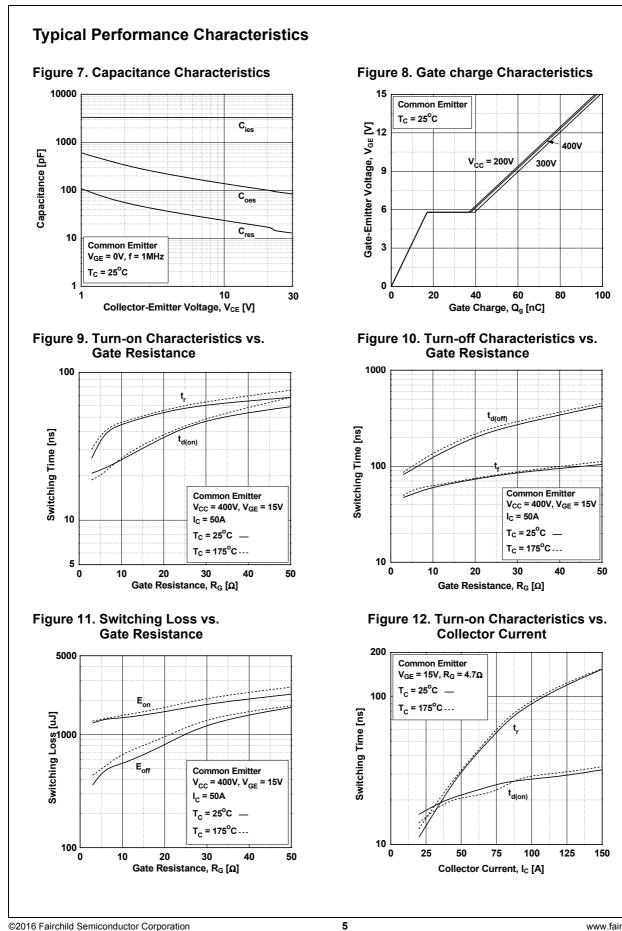


Figure 6. Saturation Voltage vs. V<sub>GE</sub>

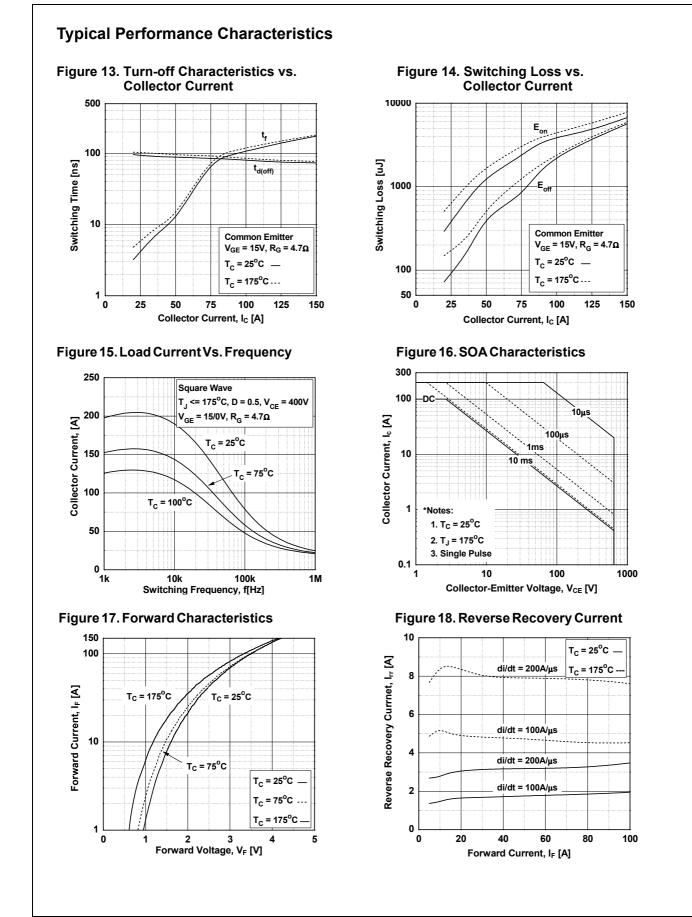


©2016 Fairchild Semiconductor Corporation FGH50T65SQD Rev. 1.0

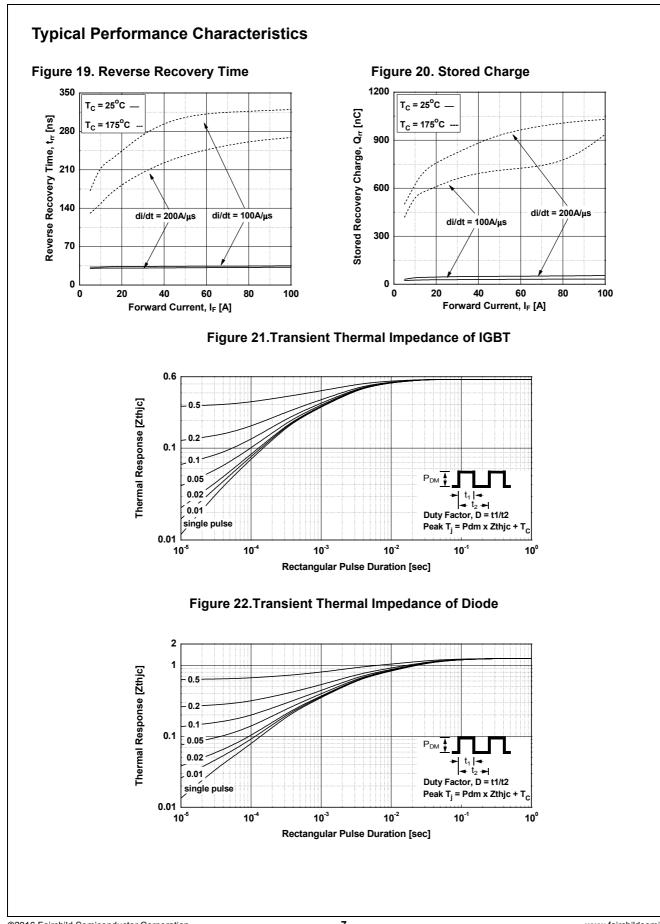


FGH50T65SQD Rev. 1.0

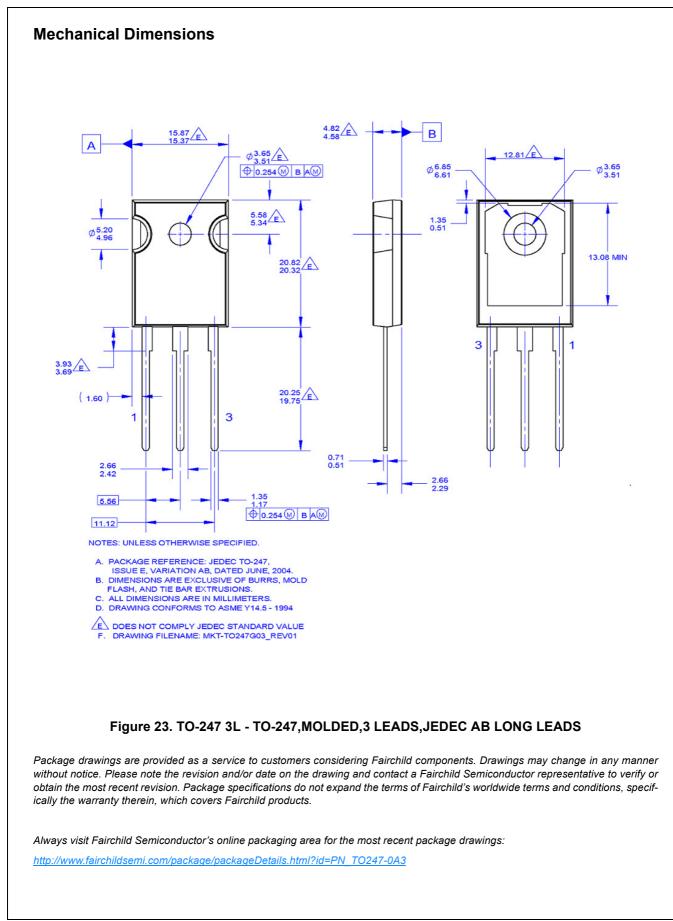
FGH50T65SQD 650 V, 50 A Field Stop Trench IGBT



©2016 Fairchild Semiconductor Corporation FGH50T65SQD Rev. 1.0



www.fairchildsemi.com





#### TRADEMARKS

The following includes registered and unregistered trademarks and service marks, owned by Fairchild Semiconductor and/or its global subsidiaries, and is not intended to be an exhaustive list of all such trademarks.

AccuPower™ AttitudeEngine™ AttitudeEngine™ Awind® AX-CAP®* BitSIC™ Build it Now™ CorePOWER™ CROSSVOLT™ CTL™ CUrrent Transfer Logic™ DEUXPED® Dual Cool™ EcoSPARK® EfficentMax™ ESBC™ FicentMax™ ESBC™ Fairchild® Fairchild® Fairchild Semiconductor® FACT Quiet Series™ FACT Quiet Series™ FACT® FastvCore™ FETBench™ FPS™	F-PFS <sup>™</sup> FRFET <sup>®</sup> Global Power Resource <sup>SM</sup> Green FPS <sup>™</sup> Green FPS <sup>™</sup> e-Series <sup>™</sup> Gmax <sup>™</sup> GTO <sup>™</sup> IntelliMAX <sup>™</sup> ISOPLANAR <sup>™</sup> Marking Small Speakers Sound Louder and Better <sup>™</sup> MegaBuck <sup>™</sup> MiCROCOUPLER <sup>™</sup> MiCrOPak <sup></sup>	© Power Supply WebDesigner <sup>™</sup> PowerTrench <sup>®</sup> PowerXS <sup>™</sup> Programmable Active Droop <sup>™</sup> QFET <sup>®</sup> QS <sup>™</sup> Quiet Series <sup>™</sup> RapidConfigure <sup>™</sup> O T <sup>™</sup> Saving our world, 1mW/W/kW at a time <sup>™</sup> SignalWise <sup>™</sup> SmartMax <sup>™</sup> SMART START <sup>™</sup> Solutions for Your Success <sup>™</sup> SPM <sup>®</sup> STEALTH <sup>™</sup> SuperSOT <sup>™</sup> -3 SuperSOT <sup>™</sup> -8 SuperSOT <sup>™</sup> -8 SupreMOS <sup>®</sup> SyncFET <sup>™</sup> Sync-Lock <sup>™</sup>	$\label{eq:system} \begin{array}{l} \textcircled{\begin{tabular}{lllllllllllllllllllllllllllllllllll$
--	---	--	---

\*Trademarks of System General Corporation, used under license by Fairchild Semiconductor.

#### DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. TO OBTAIN THE LATEST, MOST '-TO-DATE DATASHEET AND PRODUCT INFORMATION, VISIT OUR WEBSITE AT <u>HTTP://WWW.FAIRCHILDSEMI.COM</u>. FAIRCHILD DOES NOT '-UME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS.

#### AUTHORIZED USE

Unless otherwise specified in this data sheet, this product is a standard commercial product and is not intended for use in applications that require extraordinary levels of quality and reliability. This product may not be used in the following applications, unless specifically approved in writing by a Fairchild officer: (1) automotive or other transportation, (2) military/aerospace, (3) any safety critical application – including life critical medical equipment – where the failure of the Fairchild product reasonably would be expected to result in personal injury, death or property damage. Customer's use of this product is subject to agreement of this Authorized Use policy. In the event of an unauthorized use of Fairchild's product, Fairchild accepts no liability in the event of product failure. In other respects, this product shall be subject to Fairchild's Worldwide Terms and Conditions of Sale, unless a separate agreement has been signed by both Parties.

#### ANTI-COUNTERFEITING POLICY

Fairchild Semiconductor Corporation's Anti-Counterfeiting Policy. Fairchild's Anti-Counterfeiting Policy is also stated on our external website, www.fairchildsemi.com, under Terms of Use

Counterfeiting of semiconductor parts is a growing problem in the industry. All manufacturers of semiconductor products are experiencing counterfeiting of their parts. Customers who inadvertently purchase counterfeit parts experience many problems such as loss of brand reputation, substandard performance, failed applications, and increased cost of production and manufacturing delays. Fairchild is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. Fairchild strongly encourages customers to purchase Fairchild parts either directly from Fairchild or from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from Fairchild directly or from Authorized Fairchild's quality standards for handling and storage and provide access to Fairchild's full range of up-to-date technical and product information. Fairchild and our Authorized Distributors will stand behind all warranties and will appropriately address and warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. Fairchild is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.

#### PRODUCT STATUS DEFINITIONS

#### **Definition of Terms**

Datasheet Identification	Product Status	Definition
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent-Marking.pdf</u>. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor haves against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly ori indirectly, any claim of personal injury or death

#### PUBLICATION ORDERING INFORMATION

#### LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800–282–9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910

Japan Customer Focus Center Phone: 81-3-5817-1050 ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

© Semiconductor Components Industries, LLC

# **Mouser Electronics**

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

ON Semiconductor: FGH50T65SQD\_F155





Общество с ограниченной ответственностью «МосЧип» ИНН 7719860671 / КПП 771901001 Адрес: 105318, г.Москва, ул.Щербаковская д.З, офис 1107

## Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

## http://moschip.ru/get-element

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

### Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж: moschip.ru moschip.ru\_4

moschip.ru\_6 moschip.ru\_9